CMOS 8-Bit Microcontroller

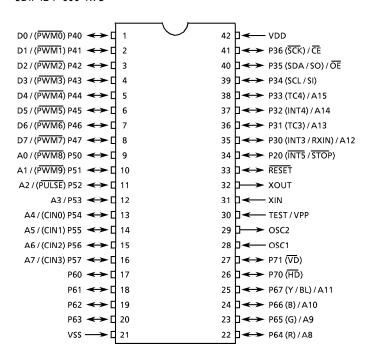
TMP87PM36N

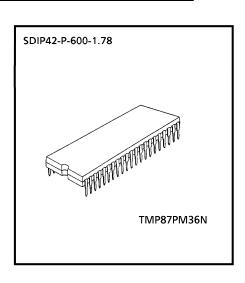
The 87PM36 is a One-Time PROM microcontroller with low-power 287.5 Kbits (a 32 Kbytes program memory and a 128 characters OSD font memory) electrically programmable read only memory for the 87CM36 system evaluation. The 87PM36 is pin compatible with the 87CM36. The operations possible with the 87CM36 can be performed by writing programs and OSD character data to PROM. The 87PM36 can write and verify in the same way as the TC57256AD using an adaptor socket BM1183A and an EPROM programmer.

Part No.	OTP RAM		Package	Adaptor Socket
TMP87PM36N	32 Kbytes + 14 × 18 × 128 bits	1 Kbytes	SDIP42-P-600-1.78	BM1183A

Pin Assignments (Top View)

SDIP42-P-600-1.78





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Pin Function

The 87PM36 has two modes: MCU and PROM.

(1) MCU mode
In this mode, the 87PM36 is pin compatible with the 87CM36 (fix the TEST pin at low level).

(2) PROM mode

Pin Name (PROM mode)	Input/Output	Functions	Pin Name (MCU mode)			
A15 to A12 A11 to A8	Input	PROM address inputs	P33 to P30 P67 to P64			
A7 to A0			P57 to P50			
D7 to D0	I/O	PROM data input/outputs	P47 to P40			
CE	Input	Chip enable signal input (active low)	P36			
ŌĒ	mput	Output enable signal input (active low)	P35			
VPP		+ 12.5 V / 5 V (Program supply voltage)	TEST			
vcc	Power supply	+5 V	VDD			
GND		ov	VSS			
P36		Pull-up with resistance for input processing				
P61		PROM mode setting pin. Be fixed at high level.				
P70						
P20	I/O					
P63, P62, P60		PROM mode setting pin. Be fixed at low level.				
P71		,				
RESET						
XIN	Input	- Connect an 8 MHz oscillator to stabilize the internal state				
XOUT	Output	Connect and Will 2 oscillator to stabilize the internal state	•			
OSC1	Input	Non connection				
OSC2	Output	Non-connection				

Operational Description

The following explains the 87PM36 hardware configuration and operation. The configuration and functions of the 87PM36 are the same as those of the 87CM36, except in that a one-time PROM is used instead of an on-chip mask ROM.

1. Operating Mode

The 87PM36 has two modes: MCU and PROM.

1.1 MCU mode

The MCU mode is activated by fixing the TEST / VPP pin at low level.

In the MCU mode, operation is the same as with the 87CM36 (the TEST / VPP pin cannot be used open because it has no built-in pull-down resistance).

1.1.1 Program memory and OSD character font memory

The 87PM36 has a 32 Kbytes of program memory and a $14 \times 18 \times 128$ bits of OSD character font memory.

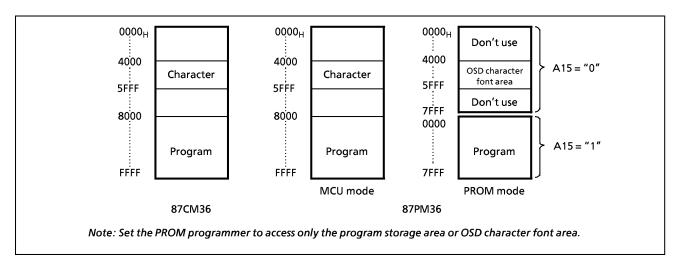


Figure 1-1. Program Memory Area

1.1.2 Data memory

The 87PM36 has an on-chip 1 Kbytes data memory (static RAM).

1.1.3 Input/output circuitry

(1) Control pins

The control pins of the 87PM36 are the same as those of the 87CM36 except that the TEST pin has no built-in pull-down resistance.

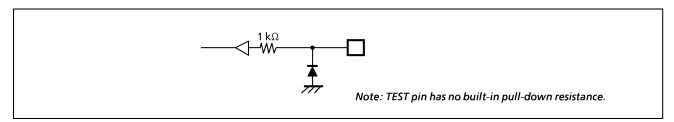


Figure 1-2. TEST Pin

(2) I/O ports

The I/O circuitries of 87PM36 I/O ports the are the same as those of the 87CM36.

Electrical Characteristics

Absolute Maximum Ratings

 $(V_{SS} = 0 V)$

Parameter	Symbol	Pins	Ratings	Unit
Supply Voltage	V_{DD}		– 0.3 to 6.5	V
Program Voltage	V _{PP}	TEST / VPP	– 0.3 to 13.0	V
Input Voltage	V _{IN}		- 0.3 to V _{DD} + 0.3	V
Output Voltage	V _{OUT1}		– 0.3 to V _{DD} + 0.3	V
Output Current (Per 1 pin)	I _{OUT1}	Ports P2, P3, P4, P5, P64 to P67, P7	3.2	
	I _{OUT2}	Ports P60 to P63	30	mA
Output Compact (Tatal)	Σ I _{OUT1}	Ports P2, P3, P4, P5, P64 to P67, P7	120	A
Output Current (Total)	Σ I _{OUT2}	Ports P60 to P63	120	mA
Power Dissipation [Topr = 70°C]	PD		600	mW
Soldering Temperature (time)	Tsld		260 (10 s)	°C
Storage Temperature	Tstg		– 55 to 125	°C
Operating Temperature	Topr		– 30 to 70	°C

Note: The absolute maximum ratings are rated values which must not be exceeded during operation, even for an instant. Any one of the ratings must not be exceeded. If any absolute maximum rating is exceeded, a device may break down or its performance may be degraded, causing it to catch fire or explode resulting in injury to the user. Thus, when designing products which include this device, ensure that no absolute maximum rating value will ever be exceeded.

Recommended Operating Conditions

 $(V_{SS} = 0 \text{ V}, \text{ Topr} = -30 \text{ to } 70^{\circ}\text{C})$

Parameter	Symbol	Pins	Conditions		Min	Max	Unit
			fc = 8MHz	NORMAL mode			
Supply Voltage	V_{DD}		IC = BIVITIZ	IDLE mode	4.5	5.5	V
	V Except hyer			STOP mode	2.0		
lawat Bab Waltana	V _{IH1}	Except hysteresis input	<u> </u>		V _{DD} × 0.70	.,	.,
Input High Voltage V _{IH2}	V _{IH2}	Hysteresis input			V _{DD} × 0.75	V _{DD}	V
Input Low Voltage	V _{IL1}	Except hysteresis input				V _{DD} × 0.30	
	V _{IL2}	Hysteresis input			0	V _{DD} × 0.25	V
	fc	XIN, XOUT	V _{DE}	₀ = 4.5 to 5.5 V	4.0	8.0	
Clock Frequency				equency mode V _{DD} = 4.5 to 5.5 V)	4.0	f _{OSC} ≦ f _C x 1.2≦8.0	MHz
	fosc	OSC1, OSC2		equency mode V _{DD} = 4.5 to 5.5 V)	2.0	$f_{OSC} \le f_C \times \\ 0.6 \le 4.0$	

Note 1: The recommended operating conditions for a device are operating conditions under which it can be guaranteed that the device will operate as specified. If the device is used under operating conditions other than the recommended operating conditions (supply voltage, operating temperature range, specified AC/DC values etc.), malfunction may occur. Thus, when designing products which include this device, ensure that the recommended operating conditions for the device are always adhered to.

Note 2: Clock frequency fc; The condition of supply voltage range is the value in NORMAL and IDLE modes.

D.C. Characteristics

 $(V_{SS} = 0 \text{ V}, \text{ Topr} = -30 \text{ to } 70^{\circ}\text{C})$

Parameter	Symbol	Pins	Conditions	Min	Тур.	Max	Unit
Hysteresis Voltage	V _{HS}	Hysteresis inputs		_	0.9	-	٧
	I _{IN1}	TEST	V _{DD} = 5.5 V, V _{IN} = 5.5 V / 0 V	_	-	± 2	
la and Comment	I _{IN2}	Open drain ports	V _{DD} = 5.5 V, V _{IN} = 5.5 V	_	-	2	١,
Input Current	I _{IN3}	Tri-state ports	V _{DD} = 5.5 V, V _{IN} = 5.5 V / 0 V	_	-	± 2	μ A
	I _{IN4}	RESET, STOP	V _{DD} = 5.5 V, V _{IN} = 5.5 V / 0 V	_	-	± 2	
Input Resistance	R _{IN2}	RESET		100	220	450	kΩ
Output Leakage		Sink open drain ports	V _{DD} = 5.5 V, V _{OUT} = 5.5 V	_	-	2	_
Current	I _{LO2}	Tri-state ports	$V_{DD} = 5.5 \text{ V}, V_{OUT} = 5.5 \text{ V} / 0 \text{ V}$	_	-	± 2	μΑ
Output High Voltage	V _{OH2}	Tri- state port	$V_{DD} = 4.5 \text{ V}, I_{OH} = -0.7 \text{ mA}$	4.1	-	-	V
Output Low Voltage	V _{OL}	Except XOUT, OSC2 and ports P60 to P63	$V_{DD} = 4.5 \text{ V}, \ \ I_{OL} = 1.6 \text{ mA}$	-	_	0.4	V
Output Low Current	I _{OL3}	Ports P60 to P63	V _{DD} = 4.5 V, V _{OL} = 1.0 V	_	20	-	mA
Supply Current in NORMAL mode			V _{DD} = 5.5 V fc = 8 MHz	-	10	16	mA
Supply Current in IDLE mode	I _{DD}		$V_{IN} = 5.3 \text{ V} / 0.2 \text{ V}$	-	6	8	mA
Supply Current in STOP mode			V _{DD} = 5.5 V V _{IN} = 5.3 V / 0.2 V	-	0.5	10	μΑ

Note 1: Typical values show those at Topr = 25° C, $V_{DD} = 5 V$.

Note 2 : Input Current I_{IN4} ; The current through pull-up resistor is not included.

Note 3: Typical current consumption during A/D conversion is 1.2mA.

A/D Conversion Characteristics

 $(V_{SS} = 0 \text{ V}, V_{DD} = 4.5 \text{ to } 5.5 \text{ V}, Topr = -30 \text{ to } 70^{\circ}\text{C})$

Parameter	Symbol	Pins	Conditions	Min	Тур.	Max	Unit
Analog Input Voltage Range	V _{AIN}	CIN3 to CIN0		V _{SS}	-	V_{DD}	V
Conversion Error			V _{DD} = 5.0 V	-	-	± 1.5	LSB

A.C. Characteristics

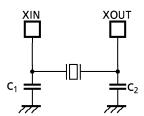
 $(V_{SS} = 0 \text{ V}, V_{DD} = 4.5 \text{ to } 5.5 \text{ V}, \text{ Topr} = -30 \text{ to } 70^{\circ}\text{C})$

Parameter	Symbol	Conditions	Min	Тур.	Max	Unit
Manhina Cuala Tima		In NORMAL mode	0.5		1.0	
Machine Cycle Time	t _{cy}	In IDLE mode	0.5	_	1.0	μS
High Level Clock Pulse Width	t _{WCH}	For external clock operation	50	_	_	ns
Low Level Clock Pulse Width	t_{WCL}	(XIN input), fc = 8MHz				113

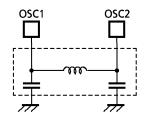
Recommended Oscillating Conditions

 $(V_{SS} = 0 \text{ V}, V_{DD} = 4.5 \text{ to } 5.5 \text{ V}, \text{ Topr} = -30 \text{ to } 70^{\circ}\text{C})$

		Oscillation		Recommend	ed Constant
Parameter	Oscillator	Frequency	Frequency Recommended Oscillator		C ₂
			KYOCERA KBR8.0M		
	Ceramic Resonator High-frequency Oscillation	8 MHz			
			KYOCERA KBR4.0MS	30pF	30pF
Oscillation		4 MHz	MURATA CSA4.00MG		
		8 MHz	TOYOCOM 210B 8.0000		
	Crystal Oscillator	4 MHz	TOYOCOM 204B 4.0000	20pF	20pF
050			TOKO A285TNIS-11695		
OSD	LC Resonator	7 MHz	TOKO TBEKSES-30375FBY	_	_



(1) High-frequency Oscillation



(2) LC Resonator for OSD

Note: On our OSD circuit, the horizontal display start position is determined by counting the clock from LC oscillator. So, the unstable start of oscillation after the rising edge of Horizontal Sync. Signal will be cause the OSD distortion.

Generally, smaller C and larger L make clearer wave form at the beginning of oscillation. We recommend that the value of LC oscillator should be equal and bigger than $33 \mu H$.

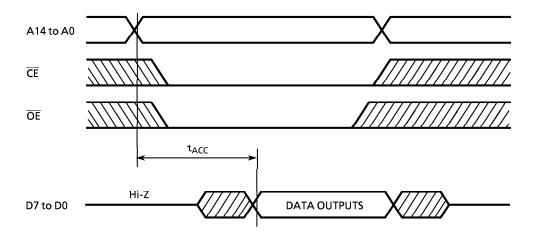
Note: To keep reliable operation, shield the device electrically with the metal plate on its package mold surface against the high electric field, for example, by CRT (Cathode Ray Tube).

D.C./A.C. Characteristics (PROM mode) (V_{SS} = 0 V)

(1) Read Operation (Ta = 25 ± 5 °C)

Parameter	Symbol	Conditions	Min	Тур.	Max	Unit
Input High Voltage	V _{IH4}		V _{CC} × 0.7	ı	V _{CC}	٧
Input Low Voltage	V_{IL4}		0	ı	$V_{CC} \times 0.12$	٧
Power Supply Voltage	V _{CC}		4.75	5.00	5.25	V
Program Power Supply Voltage	V_{PP}		V _{CC} – 0.6	V_{CC}	V _{CC} + 0.6	V
Address Access Time	t _{ACC}	V _{CC} = 5.0 ± 0.25 V	_	1.5 tcyc + 300	-	ns

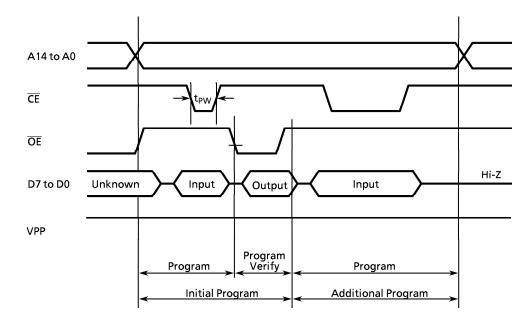
Note: tcyc = 500 ns at 8 MHz



Timing Waveforms of Read operation

(2) High-Speed Programming Operation (High speed write mode- I) (Ta = 25 ± 5 °C)

Parameter	Symbol	Conditions	Min	Тур.	Max	Unit
Input High Voltage	V _{IH4}		V _{CC} × 0.7	ı	V _{CC}	٧
Input Low Voltage	V _{IL4}		0	ı	V _{CC} × 0.12	٧
Power Supply Voltage	V _{CC}		5.75	6.0	6.25	٧
Program Power Supply Voltage	V _{PP}		12.0	12.5	13.0	V
Initial Program Pulse Width	t _{PW}	$V_{CC} = 6.0 \pm 0.25 \text{ V},$ $V_{PP} = 12.5 \pm 0.25 \text{ V}$	0.95	1.0	1.05	ms



Timing Waveforms of Programming Operation

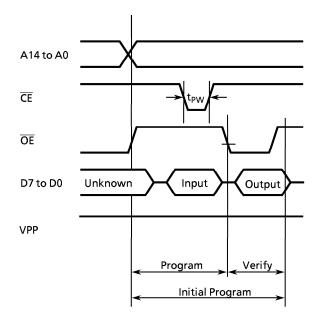
Note 1: When V_{cc} power supply is turned on or after, V_{pp} must be increased. When V_{cc} power supply is turned off or before, V_{pp} must be increased.

Note 2: he device must not be set to the EPROM programmer or picked op from it under applying the program voltage (12.5 V \pm 0.5 V = V) to the V_{pp} pin as the device is damaged.

Note 3: Be sure to execute the recommended programing mode with the recommended programing adaptor. If a mode or an adaptor except the above, the misoperation sometimes occurs.

(3) PROGRAM OPERATION (High speed write mode -II) (Topr = 25 ± 5 °C)

Parameter	Symbol	Conditions	Min	Тур.	Max	Unit
Input High Voltage	V _{IH4}		V _{CC} × 0.7	-	V _{CC}	٧
Input Low Voltage	V _{IL4}		0	_	V _{CC} × 0.12	V
Supply Voltage	V _{CC}		6.00	6.25	6.50	٧
Program Supply Voltage	V _{PP}		12.50	12.75	13.0	٧
Initial Program Pulse Width	t _{PW}	$V_{CC} = 6.25 \text{ V} \pm 0.25 \text{ V},$ $V_{PP} = 12.75 \text{ V} \pm 0.25 \text{ V}$	0.095	0.1	0.105	ms



- Note 1: When V_{cc} power supply is turned on or after, V_{pp} must be increased. When V_{cc} power supply is turned off or before, V_{pp} must be decreased.
- Note 2: The device must not be set to the EPROM programmer or picked up from it under applying the program voltage (12.75 V \pm 0.5 V) to the V_{pp} pin as the device is damaged.
- Note 3: Be sure to execute the recommended programing mode with the recommended programing adaptor. If a mode or an adaptor except the above, the misoperation sometimes occurs.